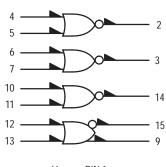
# **Quad 2-Input NOR Gate**

The MC10H102 is a quad 2–input NOR gate. The MC10H102 provides one gate with OR/NOR outputs. This MECL 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increases in power– supply current.

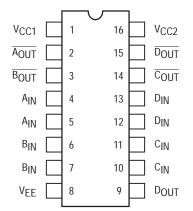
- Propagation Delay, 1.0 ns Typical
- Power Dissipation 25 mW/Gate (same as MECL 10K)
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- Voltage Compensated
- MECL 10K–Compatible



LOGIC DIAGRAM





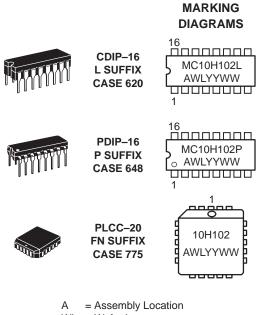


Pin assignment is for Dual–in–Line Package. For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).



## **ON Semiconductor**

http://onsemi.com



A = Assembly Location WL = Wafer Lot YY = Year WW = Work Week

### **ORDERING INFORMATION**

Device	Package	Shipping		
MC10H102L	CDIP-16	25 Units/Rail		
MC10H102P	PDIP-16	25 Units/Rail		
MC10H102FN	PLCC-20	46 Units/Rail		

# MC10H102

### MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
VEE	Power Supply ( $V_{CC} = 0$ )	-8.0 to 0	Vdc
VI	Input Voltage (V <sub>CC</sub> = 0)	0 to V <sub>EE</sub>	Vdc
lout	Output Current – Continuous – Surge	50 100	mA
TA	Operating Temperature Range	0 to +75	°C
T <sub>stg</sub>	Storage Temperature Range – Plastic – Ceramic	−55 to +150 −55 to +165	°C ℃

## **ELECTRICAL CHARACTERISTICS** (V<sub>EE</sub> = $-5.2 \text{ V} \pm 5\%$ ) (See Note 1.)

		<b>0</b> °		<b>25</b> °		<b>75</b> °		
Symbol	Characteristic	Min	Max	Min	Мах	Min	Max	Unit
ΙE	Power Supply Current	-	29	-	26	-	29	mA
l <sub>inH</sub>	Input Current High	-	425	-	265	-	265	μΑ
l <sub>inL</sub>	Input Current Low	0.5	-	0.5	-	0.3	-	μΑ
VOH	High Output Voltage	-1.02	-0.84	-0.98	-0.81	-0.92	-0.735	Vdc
VOL	Low Output Voltage	-1.95	-1.63	-1.95	-1.63	-1.95	-1.60	Vdc
VIH	High Input Voltage	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
VIL	Low Input Voltage	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc

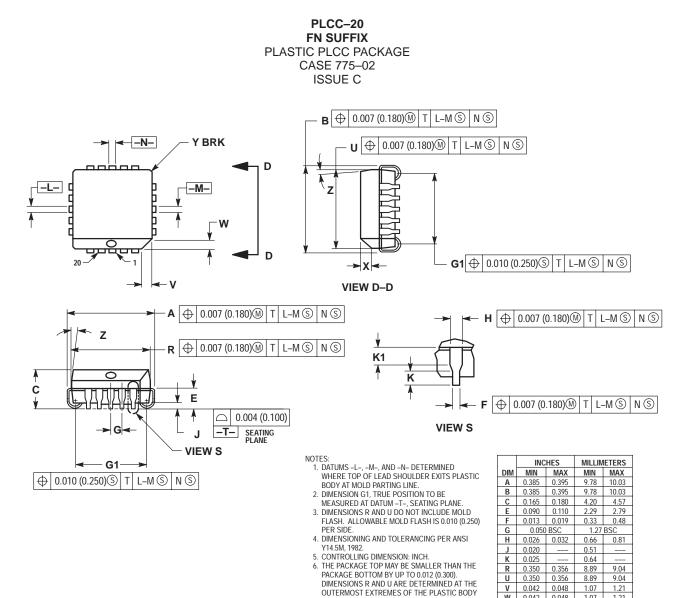
## AC PARAMETERS

<sup>t</sup> pd	Propagation Delay	0.4	1.25	0.4	1.25	0.4	1.4	ns
tr	Rise Time	0.5	1.5	0.5	1.6	0.55	1.7	ns
t <sub>f</sub>	Fall Time	0.5	1.5	0.5	1.6	0.55	1.7	ns

 Each MECL 10H series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts.

## MC10H102

#### PACKAGE DIMENSIONS



EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT

INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025

. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR

7.

(0.635).

W 0.042 0.048

X 0.042 0.056 Y ---- 0.020

----2 °

G1 0.310 0.330

K1 0.040

10

Ζ

1.07

1.07

----2 °

7.88 8.38

1.02

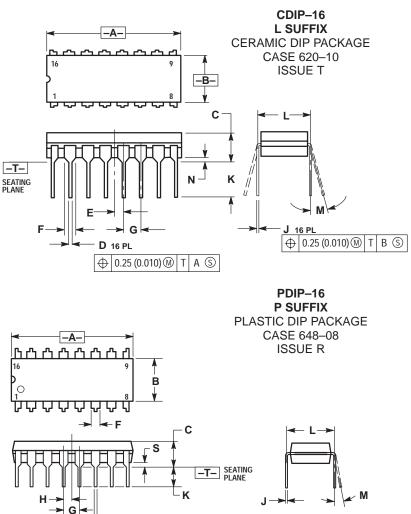
1.21

1.42

0.50

10 °

## MC10H102



#### NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEAD WHEN 3
- FORMED PARALLEL. DIMENSION F MAY NARROW TO 0.76 (0.030)
- 4 WHERE THE LEAD ENTERS THE CERAMIC BODY

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Е	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC 8	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
К	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62 BSC		
М	0 °	15 °	0 °	15 °	
Ν	0.020	0.040	0.51	1.01	

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100 BSC		2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
К	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
М	0°	10 °	0 °	10 °	
S	0.020	0.040	0.51	1.01	

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